

# 1SMA5.0AT3 Series

## 400 Watt Peak Power Zener Transient Voltage Suppressors

### Unidirectional\*

The SMA series is designed to protect voltage sensitive components from high voltage, high energy transients. They have excellent clamping capability, high surge capability, low zener impedance and fast response time. The SMA series is supplied in ON Semiconductor's exclusive, cost-effective, highly reliable Surmetic™ package and is ideally suited for use in communication systems, automotive, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications.

#### Features

- Working Peak Reverse Voltage Range – 5.0 V to 78 V
- Standard Zener Breakdown Voltage Range – 6.7 V to 91.25 V
- Peak Power – 400 W @ 1 ms
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- Response Time is Typically < 1 ns
- Flat Handling Surface for Accurate Placement
- Package Design for Top Slide or Bottom Circuit Board Mounting
- Low Profile Package
- Pb-Free Packages are Available

#### Mechanical Characteristics:

**CASE:** Void-free, transfer-molded plastic

**FINISH:** All external surfaces are corrosion resistant and leads are readily solderable

**MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:**  
260°C for 10 Seconds

**POLARITY:** Cathode indicated by molded polarity notch or polarity band

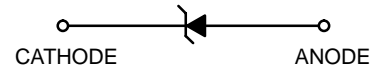
**MOUNTING POSITION:** Any



**ON Semiconductor®**

<http://onsemi.com>

### PLASTIC SURFACE MOUNT ZENER OVERVOLTAGE TRANSIENT SUPPRESSORS 5.0 – 78 V, 400 W PEAK POWER



**SMA  
CASE 403D  
PLASTIC**

#### MARKING DIAGRAM



- xx = Device Code (Refer to page 3)
- A = Assembly Location
- Y = Year
- WW = Work Week
- = Pb-Free Package

#### ORDERING INFORMATION

Device	Package	Shipping†
1SMAxxAT3	SMA	5000/Tape & Reel
1SMAxxAT3G	SMA (Pb-Free)	5000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 3 of this data sheet.

# 1SMA5.0AT3 Series

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation (Note 1) @ $T_L = 25^\circ\text{C}$ , Pulse Width = 1 ms	$P_{PK}$	400	W
DC Power Dissipation @ $T_L = 75^\circ\text{C}$ Measured Zero Lead Length (Note 2) Derate Above $75^\circ\text{C}$	$P_D$	1.5	W
Thermal Resistance from Junction to Lead	$R_{\theta JL}$	20 50	mW/ $^\circ\text{C}$ $^\circ\text{C}/\text{W}$
DC Power Dissipation (Note 3) @ $T_A = 25^\circ\text{C}$ Derate Above $25^\circ\text{C}$	$P_D$	0.5	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	4.0 250	mW/ $^\circ\text{C}$ $^\circ\text{C}/\text{W}$
Forward Surge Current (Note 4) @ $T_A = 25^\circ\text{C}$	$I_{FSM}$	40	A
Operating and Storage Temperature Range	$T_J, T_{stg}$	-65 to +150	$^\circ\text{C}$

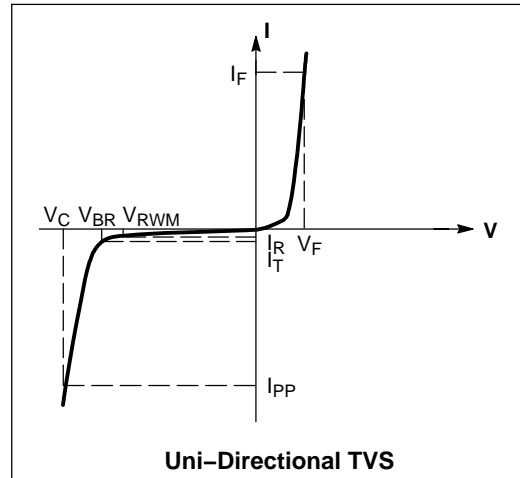
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 10 X 1000  $\mu\text{s}$ , non-repetitive.
- 1" square copper pad, FR-4 board.
- FR-4 board, using ON Semiconductor minimum recommended footprint, as shown in 403B case outline dimensions spec.
- 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute maximum.

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted,  $V_F = 3.5\text{ V Max.}$  @  $I_F = 30\text{ A}$  for all types) (Note 5)

Symbol	Parameter
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Working Peak Reverse Voltage
$I_R$	Maximum Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$

- 1/2 sine wave or equivalent, PW = 8.3 ms, non-repetitive duty cycle.



# 1SMA5.0AT3 Series

## ELECTRICAL CHARACTERISTICS

Device	Device Marking	V <sub>RWM</sub> (Note 6) Volts	I <sub>R</sub> @ V <sub>RWM</sub> μA	Breakdown Voltage			V <sub>C</sub> @ I <sub>PP</sub> (Note 8)		C Typ. (Note 9) pF	
				V <sub>BR</sub> (Volts) (Note 7)			@ I <sub>T</sub>	V <sub>C</sub>		I <sub>PP</sub>
				Min	Nom	Max	mA	Volts		Amps
1SMA5.0AT3, G	QE	5.0	400	6.4	6.7	7.0	10	9.2	43.5	2035
1SMA6.0AT3, G	QG	6.0	400	6.67	7.02	7.37	10	10.3	38.8	1730
1SMA6.5AT3, G	QK	6.5	250	7.22	7.6	7.98	10	11.2	35.7	1605
1SMA7.0AT3, G	QM	7.0	250	7.78	8.19	8.6	10	12.0	33.3	1505
1SMA7.5AT3, G	QP	7.5	50	8.33	8.77	9.21	1	12.9	31.0	1415
1SMA8.0AT3, G	QR	8.0	25	8.89	9.36	9.83	1	13.6	29.4	1035
1SMA8.5AT3, G	QT	8.5	5.0	9.44	9.92	10.4	1	14.4	27.8	1265
1SMA9.0AT3, G	QV	9.0	2.5	10	10.55	11.1	1	15.4	26.0	1200
1SMA10AT3, G	QX	10	2.5	11.1	11.7	12.3	1	17.0	23.5	1090
1SMA11AT3, G	QZ	11	2.5	12.2	12.85	13.5	1	18.2	22.0	1000
1SMA12AT3, G	RE	12	2.5	13.3	14.0	14.7	1	19.9	20.1	925
1SMA13AT3, G	RG	13	2.5	14.4	15.15	15.9	1	21.5	18.6	860
1SMA15AT3, G	RM	15	2.5	16.7	17.6	18.5	1	24.4	16.4	758
1SMA16AT3, G	RP	16	2.5	17.8	18.75	19.7	1	26.0	15.4	715
1SMA17AT3, G	RR	17	2.5	18.9	19.9	20.9	1	27.6	14.5	680
1SMA18AT3, G	RT	18	2.5	20	21.05	22.1	1	29.2	13.7	645
1SMA20AT3, G	RV	20	2.5	22.2	23.35	24.5	1	32.4	12.3	585
1SMA22AT3, G	RX	22	2.5	24.4	25.65	26.9	1	35.5	11.3	540
1SMA24AT3, G	RZ	24	2.5	26.7	28.1	29.5	1	38.9	10.3	500
1SMA26AT3, G	SE	26	2.5	28.9	30.4	31.9	1	42.1	9.5	460
1SMA28AT3, G	SG	28	2.5	31.1	32.75	34.4	1	45.4	8.8	430
1SMA30AT3, G	SK	30	2.5	33.3	35.05	36.8	1	48.4	8.3	405
1SMA33AT3, G	SM	33	2.5	36.7	38.65	40.6	1	53.3	7.5	375
1SMA36AT3, G	SP	36	2.5	40	42.1	44.2	1	58.1	6.9	345
1SMA40AT3, G	SR	40	2.5	44.4	46.75	49.1	1	64.5	6.2	315
1SMA43AT3, G	ST	43	2.5	47.8	50.3	52.8	1	69.4	5.8	295
1SMA45AT3, G	SV	45	2.5	50	52.65	55.3	1	72.2	5.5	280
1SMA48AT3, G	SX	48	2.5	53.3	56.1	58.9	1	77.4	5.2	265
1SMA51AT3, G	SZ	51	2.5	56.7	59.7	62.7	1	82.4	4.9	250
1SMA54AT3, G	TE	54	2.5	60	63.15	66.3	1	87.1	4.6	240
1SMA58AT3, G	TG	58	2.5	64.4	67.8	71.5	1	93.6	4.3	225
1SMA64AT3, G	TM	64	2.5	71.1	74.85	78.6	1	103	3.9	205
1SMA70AT3, G	TP	70	2.5	77.8	81.9	86.0	1	113	3.5	190
1SMA75AT3, G	TR	75	2.5	83.3	87.7	92.1	1	121	3.3	180

6. A transient suppressor is normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal to or greater than the DC or continuous peak operating voltage level.

7. V<sub>BR</sub> measured at pulse test current I<sub>T</sub> at an ambient temperature of 25°C.

8. Surge current waveform per Figure 2 and derate per Figure 3.

9. Bias voltage = 0 V, F = 1.0 MHz, T<sub>J</sub> = 25°C.

†Please see 1SMA10CAT3 to 1SMA75CAT3 for Bidirectional devices.

\*The "G" suffix indicates Pb-Free package available.

# 1SMA5.0AT3 Series

## RATING AND TYPICAL CHARACTERISTIC CURVES

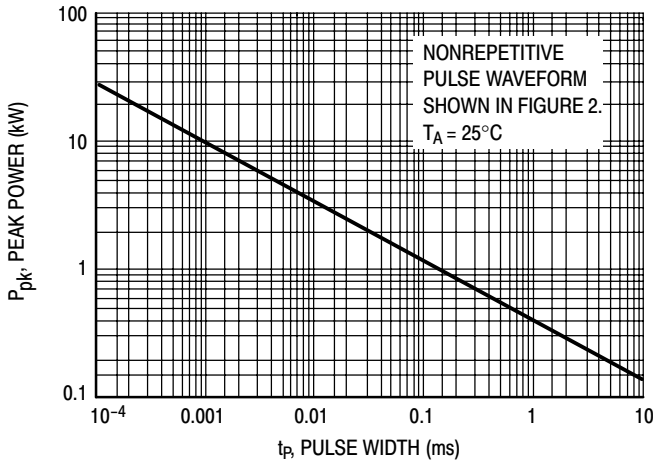


Figure 1. Pulse Rating Curve

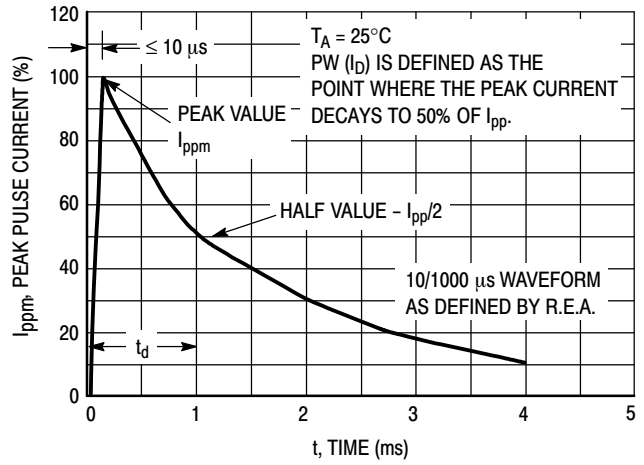


Figure 2. Pulse Waveform

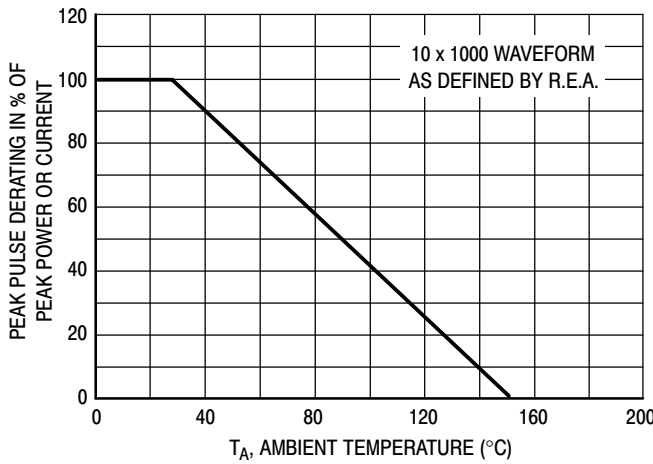


Figure 3. Pulse Derating Curve

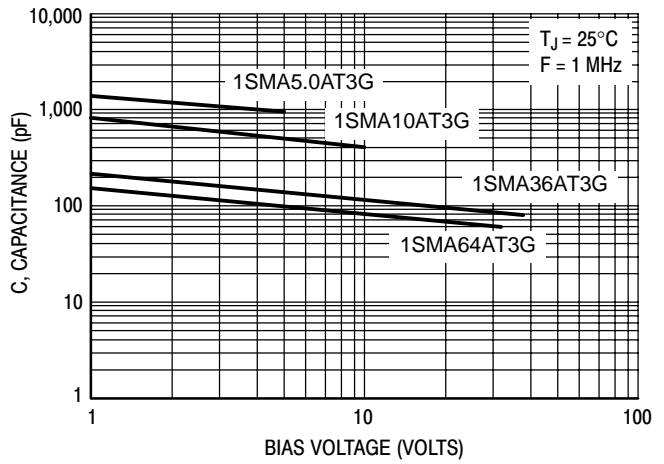


Figure 4. Typical Junction Capacitance vs. Bias Voltage

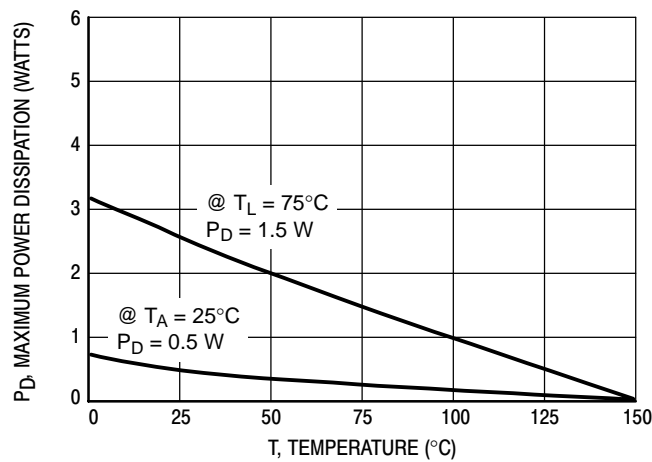
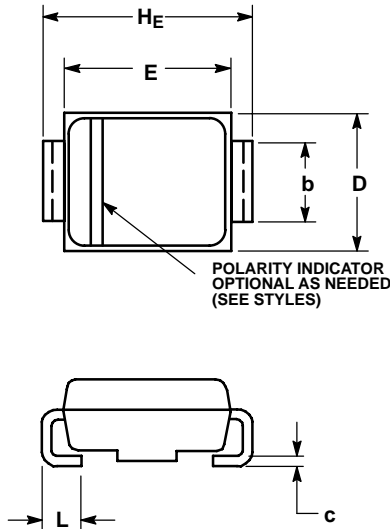


Figure 5. Steady State Power Derating

# 1SMA5.0AT3 Series

## PACKAGE DIMENSIONS

SMA  
CASE 403D-02  
ISSUE C

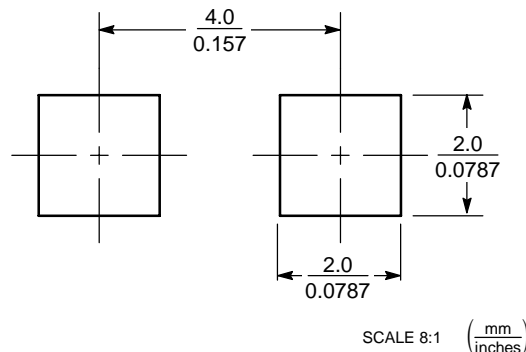


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. 403D-01 OBSOLETE, NEW STANDARD IS 403D-02.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.91	2.16	2.41	0.075	0.085	0.095
A1	0.05	0.10	0.15	0.002	0.004	0.006
b	1.27	1.45	1.63	0.050	0.057	0.064
c	0.15	0.28	0.41	0.006	0.011	0.016
D	2.29	2.60	2.92	0.090	0.103	0.115
E	4.06	4.32	4.57	0.160	0.170	0.180
HE	4.83	5.21	5.59	0.190	0.205	0.220
L	0.76	1.14	1.52	0.030	0.045	0.060


- STYLE 1:  
PIN 1. CATHODE (POLARITY BAND)  
2. ANODE

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SURMETIC is a trademark of Semiconductor Components Industries, LLC.

ON Semiconductor and  are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### PUBLICATION ORDERING INFORMATION

**LITERATURE FULFILLMENT:**  
Literature Distribution Center for ON Semiconductor  
P.O. Box 5163, Denver, Colorado 80217 USA  
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
Email: orderlit@onsemi.com

**N. American Technical Support:** 800-282-9855 Toll Free  
USA/Canada  
**Europe, Middle East and Africa Technical Support:**  
Phone: 421 33 790 2910  
**Japan Customer Focus Center**  
Phone: 81-3-5773-3850

**ON Semiconductor Website:** [www.onsemi.com](http://www.onsemi.com)  
**Order Literature:** <http://www.onsemi.com/orderlit>

For additional information, please contact your local Sales Representative